

Product data sheet

1. General description

Planar passivated AC Thyristor Triac power switch in a SOT186A (TO-220F) "full pack" plastic package with self-protective capabilities against low and high energy transients. This triac will commutate the full RMS current at the maximum rated junction temperature ($T_{j(max)}$ = 150 °C) without the aid of a snubber. It is used in applications where "high junction operating temperature capability" is required.

2. Features and benefits

- · Clamping structure ensuring safe high over-voltage withstand capability
- High junction operating temperature capability
- Full cycle AC conduction
- Isolated mounting base package
- Less sensitive gate for high noise immunity
- Over-voltage withstand capability to IEC 61000-4-5
- Pin compatible with standard triacs
- Planar passivated for voltage ruggedness and reliability
- Safe clamping capability for low energy over-voltage transients
- Self-protective turn-on during high energy voltage transients
- · Triggering in three quadrants only
- Very high immunity to false turn-on by dV/dt

3. Applications

- AC fan, pump and compressor controls
- Highly inductive, resistive and safety loads
- Large and small appliances (White Goods)
- Reversing induction motor controls
- · Applications subject to high temperature

4. Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V _{DRM}	repetitive peak off- state voltage		-	-	800	V
I _{T(RMS)}	RMS on-state current	full sine wave; $T_h \le 83 \text{ °C}$; Fig. 1; Fig. 2; Fig. 3	-	-	12	A
I _{TSM}	non-repetitive peak on- state current	full sine wave; T _{j(init)} = 25 °C; t _p = 20 ms; <u>Fig. 4; Fig. 5</u>	-	-	120	A
		full sine wave; $T_{j(init)}$ = 25 °C; t _p = 16.7 ms	-	-	132	A

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Symbol	Parameter	Conditions	М	in Typ	Max	Unit
Tj	junction temperature		-	-	150	°C
V _{PP}	peak pulse voltage	T _j = 25 °C; non-repetitive, off-state; Fig. 6	-	-	2	kV
Static chara	acteristics		· · ·			
I _{GT} gate	gate trigger current	V _D = 12 V; I _T = 100 mA; LD+ G+; T _j = 25 °C; <u>Fig. 8</u>	-	-	35	mA
		V _D = 12 V; I _T = 100 mA; LD+ G-; T _j = 25 °C; <u>Fig. 8</u>	-	-	35	mA
		V_D = 12 V; I _T = 100 mA; LD- G-; T _j = 25 °C; <u>Fig. 8</u>	-	-	35	mA
I _H	holding current	V _D = 12 V; T _j = 25 °C; <u>Fig. 10</u>	-	-	50	mA
V _T	on-state voltage	I _T = 17 A; T _j = 25 °C; <u>Fig. 11</u>	-	1.25	5 1.5	V
V _{CL}	clamping voltage	I _{CL} = 0.1 mA; t _p = 1 ms; T _j = 25 °C	85	50 -	-	V
Dynamic ch	naracteristics				·	
dV _D /dt	rate of rise of off-state voltage	V_{DM} = 536 V; T _j = 150 °C; (V _{DM} = 67% of V _{DRM}); exponential waveform; gate open circuit	50	00 -	-	V/µs
dl _{com} /dt	rate of change of commutating current	V_D = 400 V; T _j = 150 °C; I _{T(RMS)} = 12 A; dV _{com} /dt = 20 V/µs; (snubberless condition); gate open circuit	5	-	-	A/ms

5. Pinning information

able 2.	Pinning inf	ormation		
Pin	Symbol	Description	Simplified outline	Graphic symbol
1	T1	main terminal 1	mb	
2	T2	main terminal 2		sym051
3	G	gate		Synton
mb	n.c.	mounting base; isolated	() (

6. Ordering information

Table 3. Ordering information						
Type number	Package	ackage				
	Name	Description	Version			
ACTT12X-800CT	TO-220F	plastic single-ended package; isolated heatsink mounted; 1 mounting hole; 3-lead TO-220 "full pack"	SOT186A			

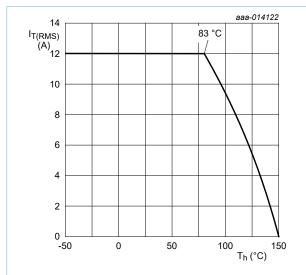
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7. Limiting values

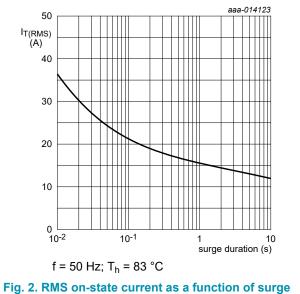
Table 4. Limiting values

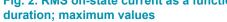
In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
V _{DRM}	repetitive peak off-state voltage		-	800	V
I _{T(RMS)}	RMS on-state current	full sine wave; $T_h \le 83 \text{ °C}$; Fig. 1; Fig. 2; Fig. 3	-	12	A
I _{TSM}	non-repetitive peak on- state current	full sine wave; $T_{j(init)}$ = 25 °C; t_p = 20 ms; Fig. 4; Fig. 5	-	120	A
		full sine wave; $T_{j(init)}$ = 25 °C; t_p = 16.7 ms	-	132	А
l ² t	I ² t for fusing	t _p = 10 ms; sine-wave pulse	-	72	A²s
dl _T /dt	rate of rise of on-state current	I _G = 0.2 A	-	100	A/µs
I _{GM}	peak gate current	t = 20 μs	-	2	А
P _{GM}	peak gate power		-	5	W
P _{G(AV)}	average gate power	over any 20 ms period	-	0.5	W
T _{stg}	storage temperature		-40	150	°C
Tj	junction temperature		-	150	°C
V _{PP}	peak pulse voltage	T _j = 25 °C; non-repetitive, off-state; <u>Fig. 6</u>	-	2	kV

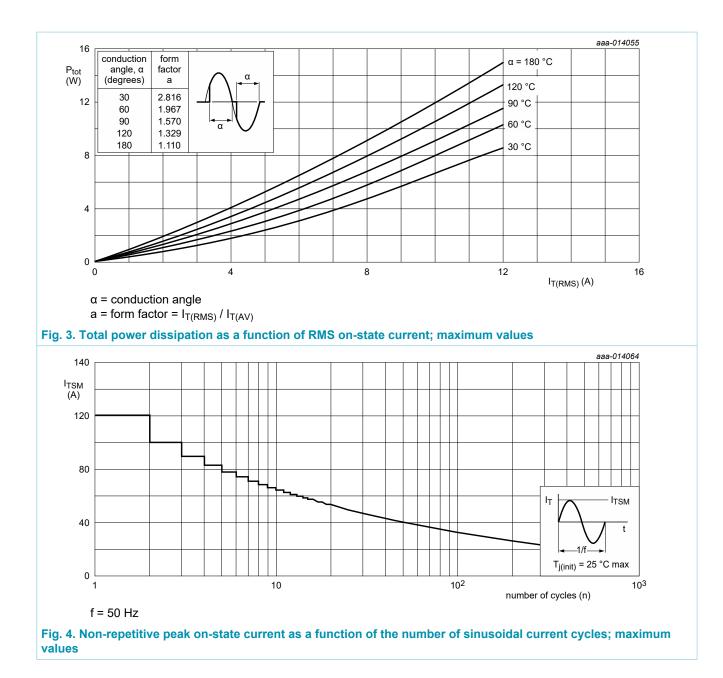






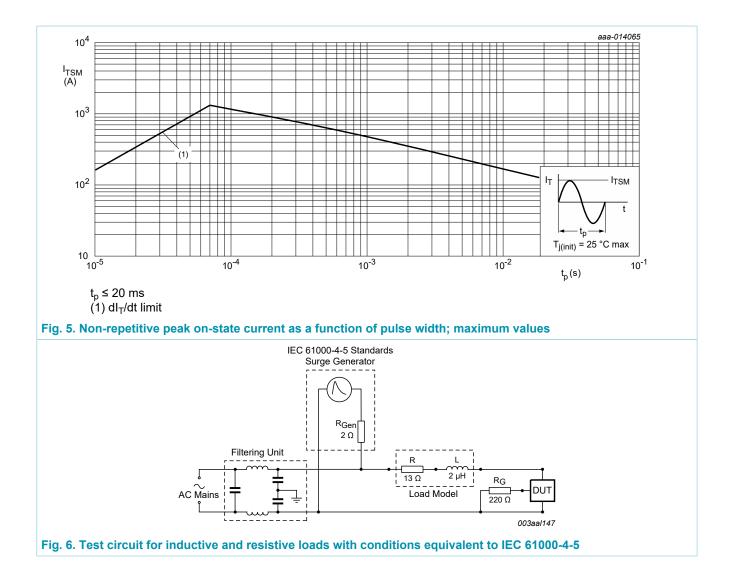


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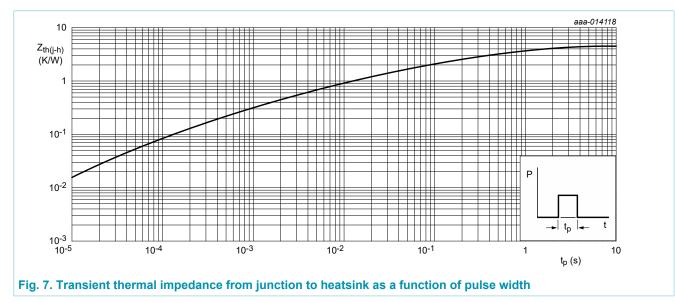
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8. Thermal characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
R _{th(j-h)}	thermal resistance from junction to heatsink	full cycle; with heatsink compound; Fig. 7	-	-	4.5	K/W
R _{th(j-a)}	thermal resistance from junction to ambient free air	in free air	-	55	-	K/W



9. Isolation characteristics

Table 6. Isolation characteristics							
Symbol	Parameter	Conditions		Min	Тур	Max	Unit
V _{isol(RMS)}	RMS isolation voltage	from all terminals to external heatsink; sinusoidal waveform; clean and dust free; 50 Hz \leq f \leq 60 Hz; T _h = 25 °C		-	-	2500	V
C _{isol}	isolation capacitance	from main terminal 2 to external heatsink; f = 1 MHz; T _h = 25 °C		-	10	-	pF

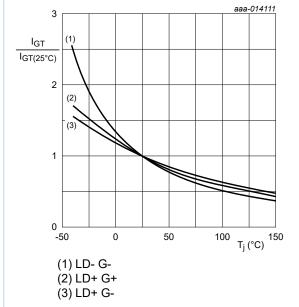
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10. Characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Static chara	acteristics					
I _{GT}	gate trigger current	V _D = 12 V; I _T = 100 mA; LD+ G+; T _j = 25 °C; <u>Fig. 8</u>	-	-	35	mA
		V _D = 12 V; I _T = 100 mA; LD+ G-; T _j = 25 °C; <u>Fig. 8</u>	-	-	35	mA
		V _D = 12 V; I _T = 100 mA; LD- G-; T _j = 25 °C; <u>Fig. 8</u>	-	-	35	mA
IL	latching current	V _D = 12 V; I _G = 100 mA; LD+ G+; T _j = 25 °C; <u>Fig. 9</u>	-	-	50	mA
		V_D = 12 V; I _G = 100 mA; LD+ G-; T _j = 25 °C; Fig. 9	-	-	70	mA
		V _D = 12 V; I _G = 100 mA; LD- G-; T _j = 25 °C; <u>Fig. 9</u>	-	-	50	mA
I _H	holding current	V _D = 12 V; T _j = 25 °C; <u>Fig. 10</u>	-	-	50	mA
V _T	on-state voltage	I _T = 17 A; T _j = 25 °C; <u>Fig. 11</u>	-	1.25	1.5	V
V _{GT}	gate trigger voltage	V _D = 12 V; I _T = 100 mA; T _j = 25 °C; <u>Fig. 12</u>	-	0.8	1	V
		V _D = 400 V; I _T = 100 mA; T _j = 150 °C; <u>Fig. 12</u>	0.2	0.45	-	V
ID	off-state current	V _D = 800 V; T _j = 25 °C	-	-	10	μA
		V _D = 800 V; T _j = 150 °C	-	-	0.5	mA
V _{CL}	clamping voltage	I _{CL} = 0.1 mA; t _p = 1 ms; T _j = 25 °C	850	-	-	V
Dynamic ch	naracteristics					
dV _D /dt	rate of rise of off-state voltage	V_{DM} = 536 V; T _j = 150 °C; (V _{DM} = 67% of V _{DRM}); exponential waveform; gate open circuit	500	-	-	V/µs
dl _{com} /dt	rate of change of commutating current	V_D = 400 V; T_j = 150 °C; $I_{T(RMS)}$ = 12 A; dV _{com} /dt = 20 V/µs; (snubberless condition); gate open circuit	5	-	-	A/m

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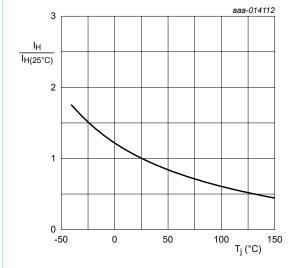
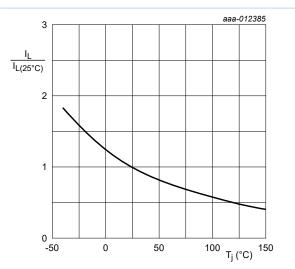
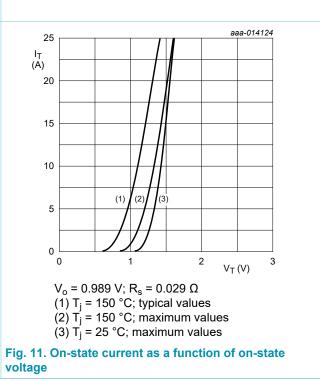


Fig. 10. Normalized holding current as a function of junction temperature

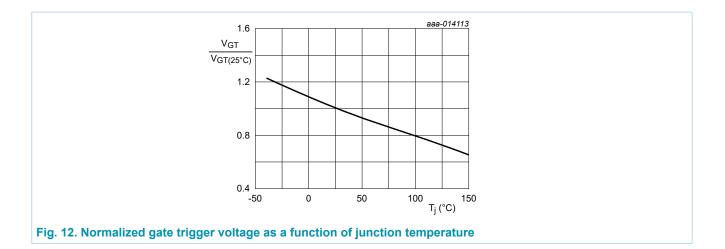






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11. Package outline

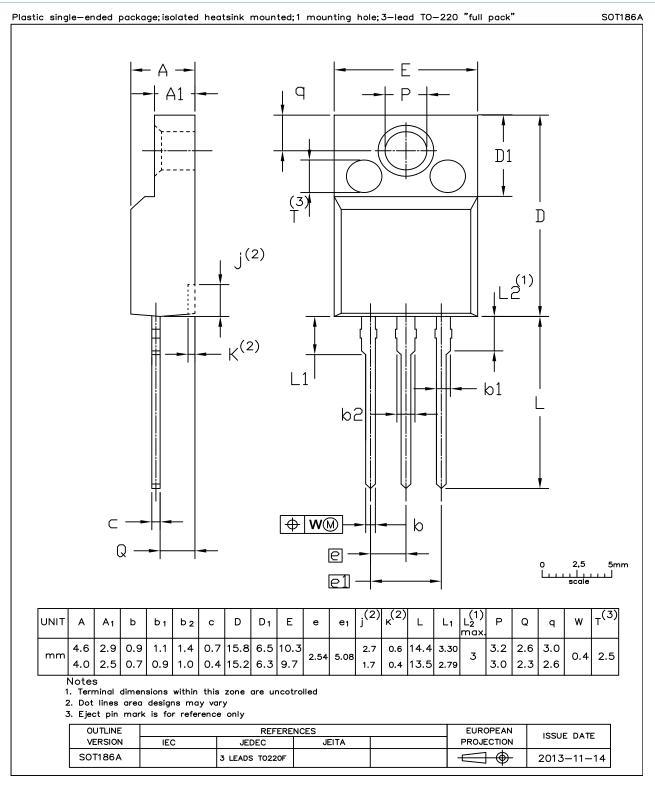


Fig. 13. Package outline TO-220F (SOT186A)

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12. Legal information

Data sheet status

Document status [1][2]	Product status [<u>3]</u>	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

 Please consult the most recently issued document before initiating or completing a design.

- [2] The term 'short data sheet' is explained in section "Definitions".
- [3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL <u>http://www.ween-semi.com</u>.

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